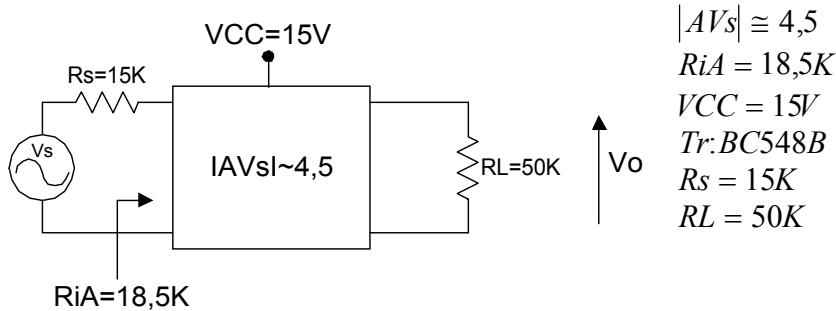


## Problema 22

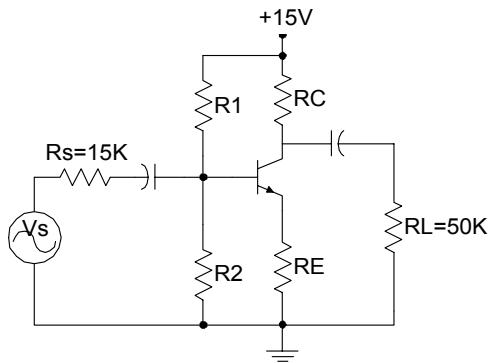
Diseñar una etapa amplificadora que tenga las siguientes características:



Calcular  $R_o$ ,  $R_{oA}$ ,  $R_{os}$  y la excursión simétrica máxima de la tensión de salida.

$$BVCE0 = 20 \Rightarrow VCC_{MAX} = 15V$$

Circuito propuesto:



$$AVS = AV \cdot \frac{R_i_A}{R_i_A + R_s} \Rightarrow AVS = \frac{AV}{1,8} = \frac{R_d}{R_E} \cdot 0,55$$

Imponemos:  $\left. \begin{array}{l} ICQ=2mA \\ VCEQ=5V \end{array} \right\} \Rightarrow \begin{array}{l} hFE=280 \\ hfe=330 \\ hie=4200\Omega \\ hoe=30\mu s \end{array}$

entonces  $AV \approx 8AVS \therefore AV \approx 8 = \frac{R_d}{R_E} \Rightarrow R_d = 8 \cdot R_E$

como  $RL \gg RC \Rightarrow R_d \approx RC \therefore AV \approx \frac{RC}{R_E} = 8 \Rightarrow RC = 8 \cdot R_E$

Luego:

$$VCC = VCEQ + ICQ \cdot (RC + RE) \Rightarrow RE = \frac{VCC - VCEQ}{9 \cdot ICQ} = 555\Omega$$

$$RC = 8 \cdot RE = 4444\Omega$$

Para que  $Ri_A = 18,5K$ :

$$Ri = hie + RE \cdot hfe \Rightarrow RE \cdot hfe = 183150\Omega \Rightarrow Ri = 187350\Omega$$

$$Ri_A = RB \parallel Ri = 18,5K \Rightarrow RB = 20526\Omega$$

Para la  $Ro$ :

$$Ro \cong \frac{1}{hoe} \cdot \left( 1 + \frac{hfe \cdot RE}{(Rs \parallel RB) + RE + hie} \right) + (RE \parallel hie) = 492K$$

$$Ro_A = Ro \parallel RC \cong RC = 4444\Omega$$

$$Ro_S = Ro \parallel Rd \cong Rd = 4081\Omega$$

Luego para hallar  $VBB$ :

$$ICQ = \frac{VBB - VBE}{RE + \frac{RB}{hFE}} \Rightarrow VBB = ICQ \cdot \left( RE + \frac{RB}{hFE} \right) + VBE = 1,96V$$

Para hallar  $R1$  y  $R2$ :

$$R1 \cdot VBB = VCC \cdot RB \Rightarrow R1 = \frac{VCC \cdot RB}{VBB} = 157358\Omega$$

$$\frac{1}{RB} = \frac{1}{R1} + \frac{1}{R2} \Rightarrow R2 = 23605\Omega$$

Valores estandarizados de los resistores:

$$R1 = 150K \quad R2 = 22K \quad RC = 4700\Omega \quad RE = 560\Omega$$

Verificación:

$$VBB = VCC \cdot \frac{R2}{R1 + R2} = 1,92V$$

$$RB = R1\|R2 = 19186\Omega$$

$$VCEQ = VCC - ICQ \cdot (RC + RE) = 4,69V$$

$$ICQ = \frac{VBB - VBE}{RE} = 2,18mA \rightarrow hFE = 290$$

$$ICQ = \frac{VBB - VBE}{RE + \frac{RB}{hFE}} = 1,95mA \rightarrow hFE = 270$$

$$AV = -\frac{Rd}{RE} \approx 7,68 \quad |AVS| = |AV| \cdot \frac{Ri_A}{Ri_A + Rs} \approx 4,14$$

$$n = \frac{RE}{\frac{RB}{hFE_{min}}} \approx 6$$

$$Ri = hie + RE \cdot hfe = 189000\Omega$$

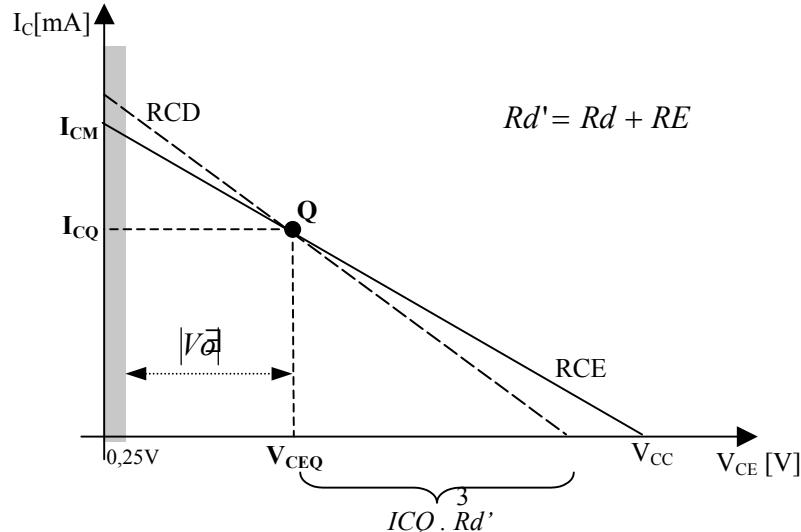
$$Ri_A = RB\|Ri = 17,5K$$

$$Ro \approx \frac{1}{hoe} \cdot \left( 1 + \frac{hfe \cdot RE}{(Rs\|RB) + RE + hie} \right) + (RE\|hie) = 500K$$

$$Ro_A = Ro\|RC \approx 4692\Omega$$

$$Ro_S = Ro\|Rd \approx 4300\Omega$$

Para la máxima excursión de  $V_o$ :



$$VCE_{SAT} = 0,25V$$

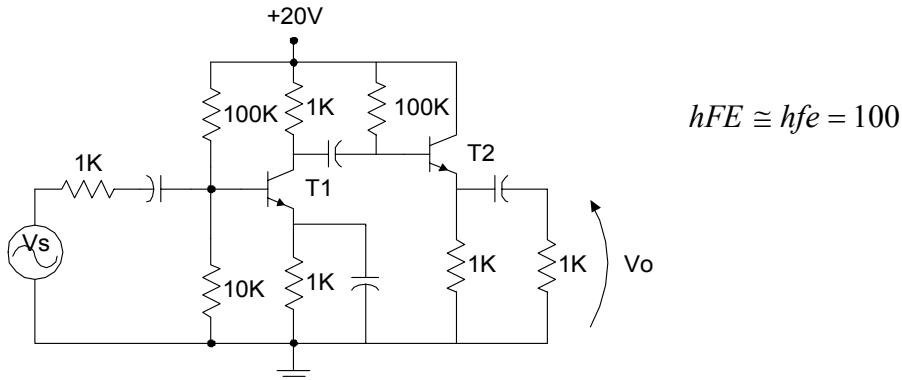
$$VCEQ - VCE_{SAT} < ICQ \cdot Rd'$$

$$4,44V < 9,48V$$

$$|V\overline{d}| = (VCEQ - VCE_{SAT}) \cdot \frac{Rd}{Rd'} = 3,9V$$

## Problema 40

Calcular la AV y la máxima amplitud simétrica de la tensión de salida del amplificador de la figura. Suponer que los transistores son idénticos y tienen un  $hFE=100$ . Graficar la recta de carga dinámica de ambos transistores.



$$AV = -gm \cdot Rd \quad \text{y además} \quad gm = \frac{1}{hib}$$

$$gm = 40 \cdot ICQ_1$$

Averiguo las corrientes de polarización:

$$\mathbf{T1)} \quad RB = R1 \parallel R2 = 9,1K$$

$$VBB = VCC \cdot \frac{R2}{R1 + R2} = 1,82V$$

$$ICQ = \frac{VBB - VBE}{RB + \frac{RE}{hFE}} = 1mA$$

$$VCEQ = VCC - IC \cdot (RC + RE) = 18V$$

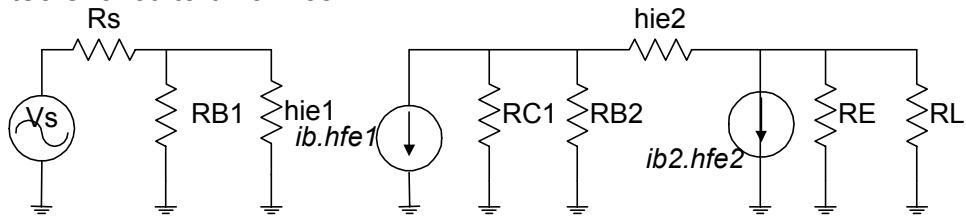
$$\mathbf{T2)} \quad RB = 100K$$

$$VCC = \frac{IC}{hFE} \cdot RB + VBE + IC \cdot RE$$

$$ICQ = \frac{VCC - VBE}{RE + \frac{RB}{hFE}} = 9,65mA$$

$$VCEQ = VCC - IC \cdot (RC + RE) = 10,35V$$

Planteo el circuito dinámico:



$$hib_1 = \frac{1}{gm_1} = 25\Omega$$

$$hib_2 = \frac{1}{gm_2} = 2,6\Omega$$

$$hie_1 = hib_1 \cdot hfe = 2,5K$$

$$hie_2 = hib_2 \cdot hfe = 260\Omega$$

$$Ri_2 = hie + (RE \cdot hfe) \parallel (RL \cdot hfe) = 260\Omega + 50K = 50260\Omega$$

$$Ri_A = RB_2 \parallel Ri_2 = 33,3K$$

Planteo de las ganancias:

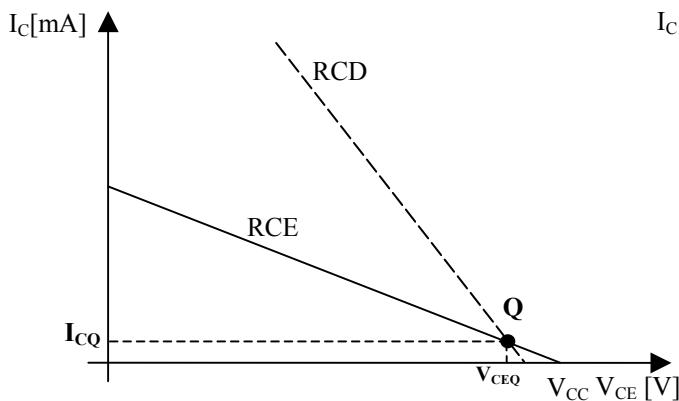
$$AV_1 = -gm \cdot Rd = -gm \cdot (RC \parallel Ri_{A2}) = -39$$

$$Ri_A = RB \parallel hie_1 = 1,96K$$

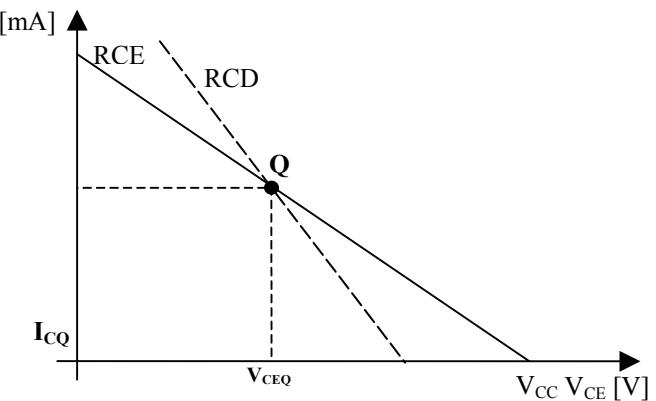
$$AV_{S1} = \frac{AV \cdot Ri_A}{Ri_A + Rs} = -25,8$$

$$AV_{S2} = \frac{Vo}{Vi_2} = \frac{(RE_2 \parallel RL) \cdot hfe}{hie + (RE_2 \parallel RL) \cdot hfe} = 0,995$$

$$AV_s = AV_{S1} \cdot AV_{S2} = -25,7$$



$$Vo = ICQ \cdot Rd = 0,97V$$



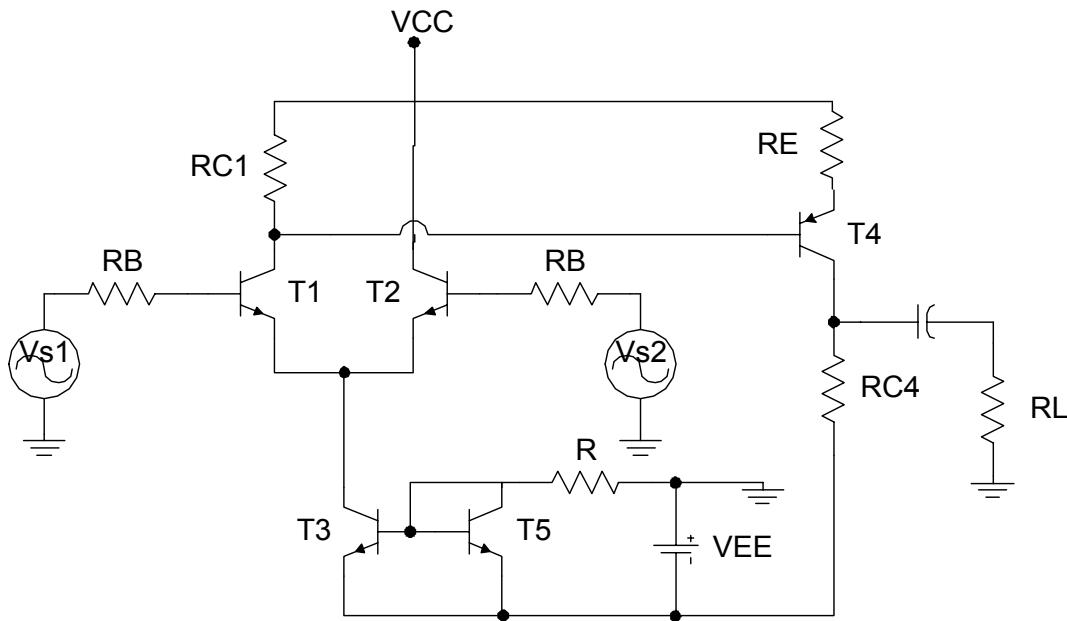
$$Vo = ICQ \cdot Rd = 4,8V$$

## Problema 41

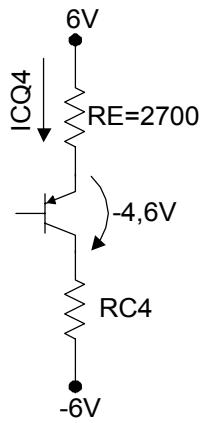
CA3086    ICQ4=1mA  
 RC1=3K3  
 VCEQ4=-4,6V  
 RL=10K

VCC=VEE=6V  
 RB=100Ω  
 RE=2700Ω

- Determinar los valores de los componentes que faltan
- Encontrar el punto Q de todos los transistores
- Calcular la ganancia de modo diferencial del sistema, Rid y Ric



a)



$$ICQ4 = 1mA$$

$$ICQ1 = \frac{VCC - VCEQ1}{RC1} = 1mA$$

$$VRE + VCEQ + VRC_4 = VCC + VEE$$

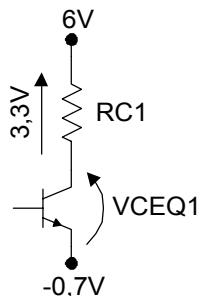
$$VRC_4 = 4,7V \quad \Rightarrow \quad RC_4 = \frac{VRC_4}{ICQ4} = \frac{4,7V}{1mA} = 4700\Omega$$

Para fijar una corriente de  $1mA$  que circule por T1 y T2 debemos calcular  $R$ :

$$ICQ_3 = 2mA \Rightarrow R = \frac{VEE - VBE}{ICQ_3 \cdot \left(1 + \frac{2}{hFE}\right)} = 2704\Omega \approx 2700\Omega$$

b)

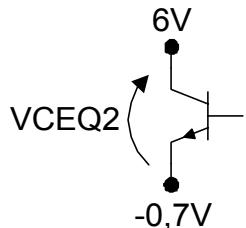
**T1:**



$$VCC - VRC_1 - VCEQ_1 = -0.7V$$

$$VCEQ_1 = VCC - VRC_1 + 0.7V = 3.4V$$

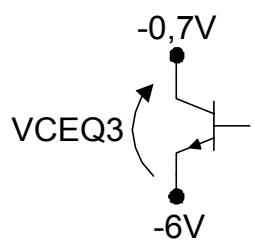
**T2:**



$$VCC - VCEQ_2 = -0.7V$$

$$VCEQ_2 = VCC + 0.7V = 6.7V$$

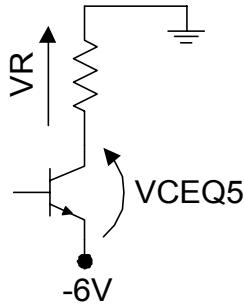
**T3:**



$$VEE = -VCEQ_3 - 0.7V$$

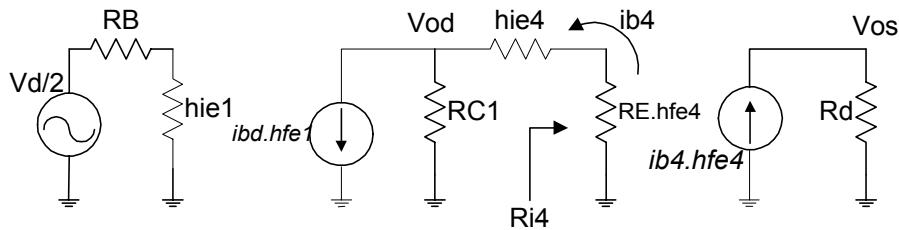
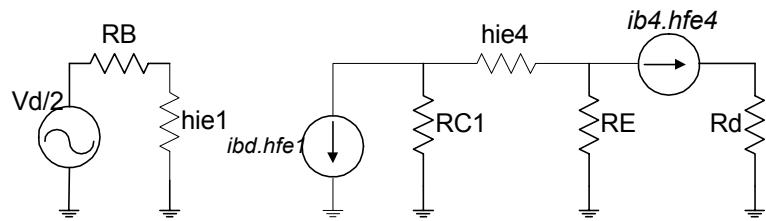
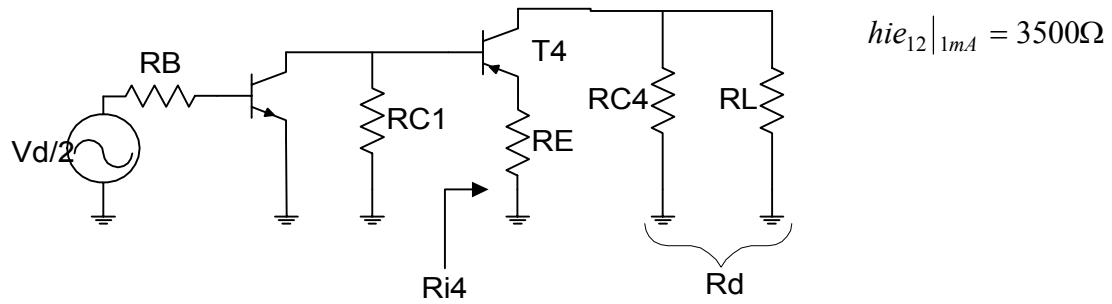
$$VCEQ_3 = -VEE + 0.7V = 5.3V$$

**T5:**



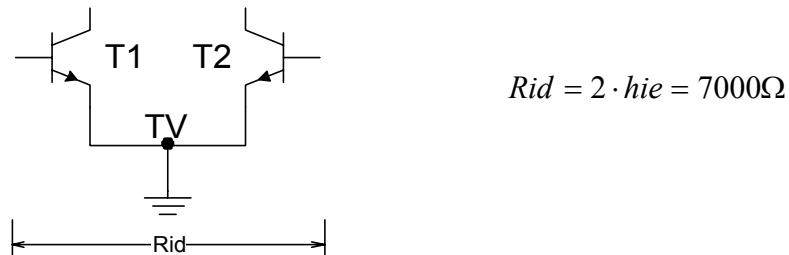
$$VCEQ_5 = VBE_5 = 0.7V$$

c) Para hallar la  $A_{Vds}$  planteamos el circuito equivalente:

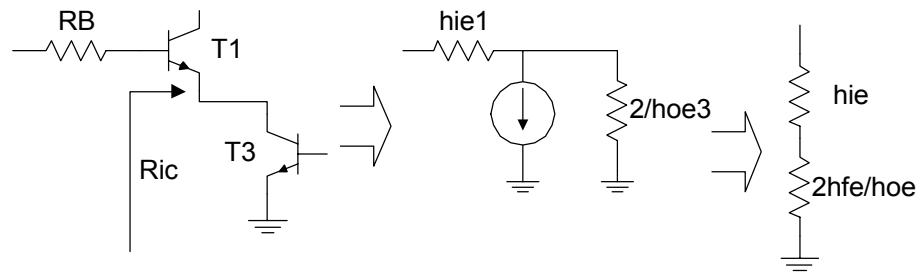


$$|AV_{ds}| = \frac{V_{os}}{V_d} = \frac{V_{os}}{V_{od}} \cdot \frac{V_{od}}{V_d} = \frac{hfe_{12} \cdot (RC_1 \| R_{i4})}{2 \cdot (RB + hie_{12})} \cdot \frac{R_d \cdot hfe_4}{(hie_4 + RE \cdot hfe_4)} \cong 53$$

Para hallar  $R_{id}$ :



Para hallar  $Ric$ :



$$Ric = hie + 2 \cdot \frac{hfe}{hoe} \cong 6,4 M\Omega \quad \text{donde} \quad hoe3 = 3,12 \cdot 10^{-5} \frac{A}{V}$$